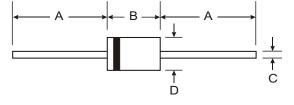


# PR1501/S - PR1505/S

#### 1.5A FAST RECOVERY RECTIFIER

#### **Features**

- **Diffused Junction**
- Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 50A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0



### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band Marking: Type Number
- DO-41 Weight: 0.3 grams (approx.) DO-15 Weight: 0.4 grams (approx.)

#### **DO-41 Plastic** DO-15 Dim Min Max Min Max Α 25.40 25.40 4.06 5.50 В 5.21 7.62 С 0.71 0.864 0.686 0.889 D 2.00 2.72 2.60 3.60 All Dimensions in mm

"S" Suffix Designates DO-41 Package No Suffix Designates DO-15 Package

## **Maximum Ratings and Electrical Characteristics**

@ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	PR 1501/S	PR 1502/S	PR 1503/S	PR 1504/S	PR 1505/S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	V
Average Rectified Output Current (Note 1) @ T <sub>A</sub> = 50°C	lo	1.5					А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Loa (JEDEC Method)	d I <sub>FSM</sub>	50					А
Forward Voltage @ I <sub>F</sub> = 1.5	V <sub>FM</sub>	1.2					V
Peak Reverse Current @ T <sub>A</sub> = 25°0 at Rated DC Blocking Voltage @ T <sub>A</sub> = 100°0		5.0 100					μА
Reverse Recovery Time (Note 3)	t <sub>rr</sub>	150 250				ns	
Typical Junction Capacitance (Note 2)	Cj	20 10				10	pF
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	35					K/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +150					°C

1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case. Notes:

- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Measured with  $I_F$  = 0.5A,  $I_R$  = 1.0A,  $I_{rr}$  = 0.25A. See figure 5.



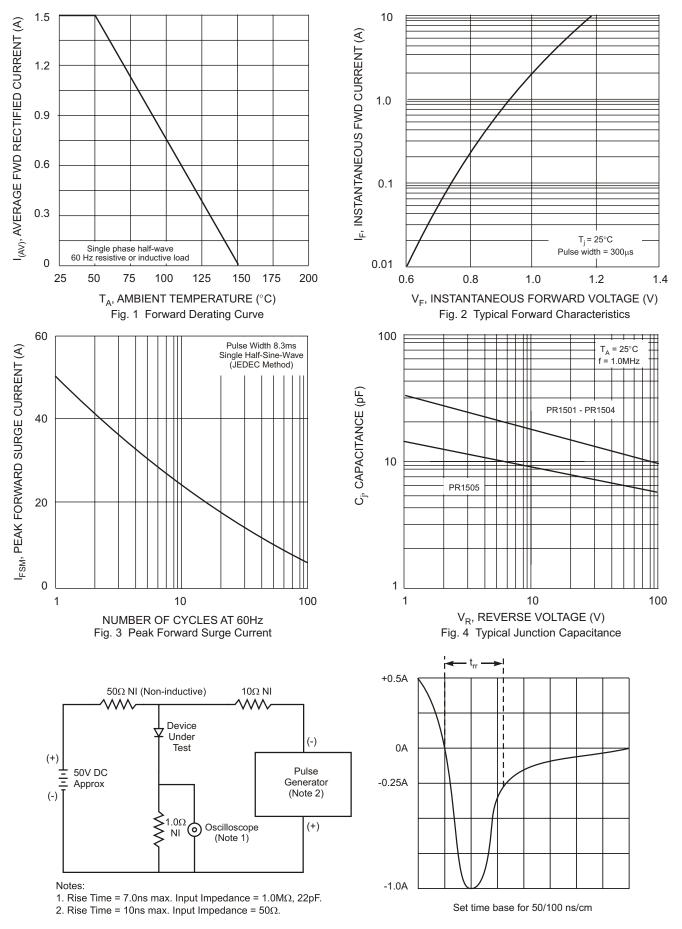


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit